June 1989

DM7160 Magnitude Comparator

General Description

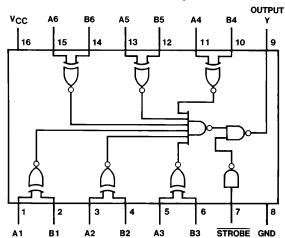
This device offers comparisons to determine equality between two binary words. The DM7160 compares two six-bit words. A strobe override is provided. When the strobe is taken to a high logic level, the output is forced to a high logic level. The device also features open-collector outputs for expansion.

Features

- Typical propagation delay 21 ns
- Typical power dissipation 205 mW
- Open-collector outputs for expansion

Connection Diagram

Dual-In-Line Package



Order Number DM7160J or DM7160W See NS Package Number J16A or W16A

TL/F/6578-1

Function Table

Condition	STROBE S	Output Y	
$A = B, A \neq B$	Н	Н	
A = B	L	Н	
$A \neq B$	L	L	

 $\mathsf{H} \,=\, \mathsf{High}\,\,\mathsf{Logic}\,\,\mathsf{Level}$

L = Low Logic Level

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage 7V
Input Voltage 5.5V
Operating Free Air Temperature Range
DM71 -55°C to +125°C

Storage Temperature Range

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	DM7160			Units
		Min	Nom	Max	Office
V_{CC}	Supply Voltage	4.5	5	5.5	V
V_{IH}	High Level Input Voltage	2			٧
V_{IL}	Low Level Input Voltage			0.8	V
V _{OH}	High Level Output Voltage			5.5	٧
I _{OL}	Low Level Output Current			16	mA
T _A	Free Air Operating Temperature	-55		125	°C

-65°C to +150°C

Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

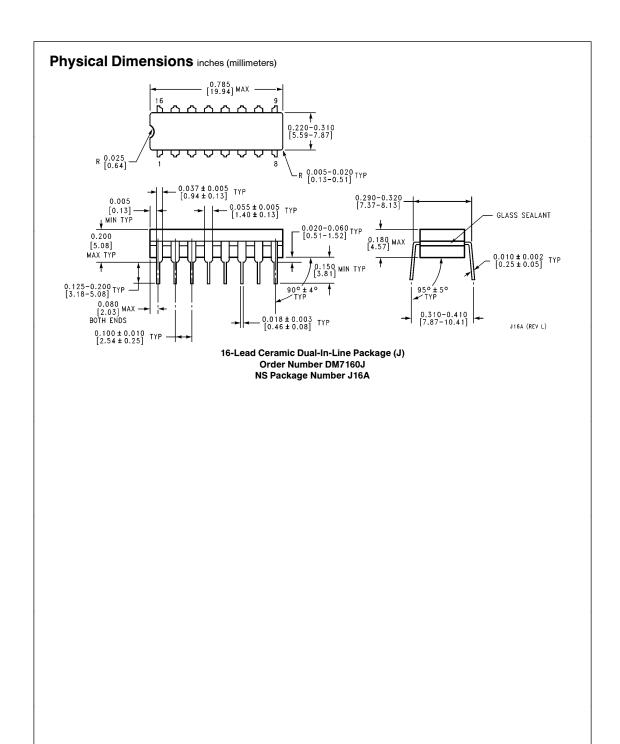
Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min, I_I = -12 mA$			-1.5	V
ICEX	High Level Output Current	$V_{CC} = Min, V_O = 5.5V$ $V_{IL} = Max$			100	μΑ
V _{OL}	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Min$		0.2	0.4	V
l _l	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$			1	mA
I _{IH}	High Level Input Current	$V_{CC} = Max, V_I = 2.4V$			40	μΑ
I _{IL}	Low Level Input Current	$V_{CC} = Max, V_I = 0.4V$			-1.6	mA
I _{CC}	Supply Current	V _{CC} = Max (Note 2)		41	60	mA

$\textbf{Switching Characteristics} \ \ \text{at V}_{CC} = 5 \text{V and T}_{A} = 25 ^{\circ}\text{C (See Section 1 for Test Waveforms and Output Load)}$

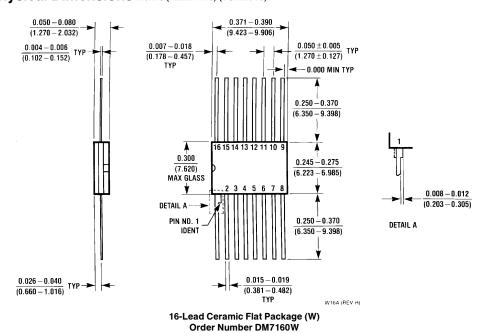
Symbol	Parameter	From (Input) To (Output)	$R_L = 400\Omega$,	11-14-	
			Min	Max	Units
t _{PLH}	Propagation Delay Time Low to High Level Output	Data to Output		25	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	Data to Output		40	ns
t _{PLH}	Propagation Delay Time Low to High Level Output	Strobe to Output		18	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	Strobe to Output		30	ns

Note 1: All typicals are at $V_{CC}=5V$, $T_A=25^{\circ}C$.

Note 2: I_{CC} is measured with all inputs grounded and all outputs open.



Physical Dimensions inches (millimeters) (Continued)



NS Package Number W16A

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